

PSMN1R5-25MLH

N-channel 25 V, 1.81 m Ω , 150 A logic level MOSFET in LFPAK33 using NextPowerS3 technology

30 September 2019

Product data sheet

1. General description

Logic level gate drive N-channel enhancement mode MOSFET in LFPAK33 package. NextPowerS3 technology delivers low R_{DSon} , low I_{DSS} leakage and high efficiency. Rated to 150 A and optimized with low gate resistance (R_{G}) for fast-switching applications.

2. Features and benefits

- Optimized for low R_{DSon} and low gate resistance (R_G)
- · Fast switching reduced switching losses
- Strong linear-mode (SOA) rating
- Low leakage < 1 µA at 25 °C
- · Low spiking and ringing for low EMI designs
- Optimized for 4.5 V gate drive
- 150 A continuous I_{D(max)} rating
- High reliability copper-clip bonded and solder die attach LFPAK33 package
- Qualified to 175 °C
- Exposed leads for optimal visual solder inspection

3. Applications

- Synchronous buck regulator
- Synchronous rectifier in AC-DC and DC-DC applications
- · BLDC (brushless) motor control
- · eFuse and battery protection
- OR-ing and hot-swap

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit			
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	25	V			
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	150	Α			
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	106	W			
Tj	junction temperature			-55	-	175	°C			
Static characte	eristics									
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 10		-	1.46	1.81	mΩ			
		V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C; Fig. 10		-	2.1	2.7	mΩ			
Dynamic chara	Dynamic characteristics									
Q_{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V;		1	5.6	11.2	nC			
Q _{G(tot)}	total gate charge	Fig. 12; Fig. 13		7.7	17	28	nC			



Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Source-drain diode							
S	softness factor	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V}; V_{DS} = 12 \text{ V}; Fig. 16$		-	0.88	-	

^{[1] 150}A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified	l outline		Graphic symbol
1	S	source				D -
2	S	source				
3	S	source				G (F)
4	G	gate				mbb076 S
mb	D	Mounting base; connected to drain	1	X33 (SOT1210)	ı	

6. Ordering information

Table 3. Ordering information

Type number	Package							
	Name	Description	Version					
PSMN1R5-25MLH	LFPAK33	Plastic, single ended surface mounted package (LFPAK33); 8 leads; 0.65 mm pitch	SOT1210					

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN1R5-25MLH	1H525L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	25	V
V_{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 175 °C; R_{GS} = 20 kΩ		-	25	V
V_{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	106	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	150	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	121	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3		-	687	Α
T _{stg}	storage temperature			-55	175	°C

Symbol	Parameter	Conditions		Min	Max	Unit
Tj	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
Source-drain die	ode		•			
Is	source current	T _{mb} = 25 °C		-	106	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 \degree C$		-	687	А
Avalanche rugg	edness		•			
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 25 A; $V_{sup} \le 25$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 811 μs	[2]	-	330	mJ
I _{AS}	non-repetitive avalanche current	$V_{sup} \le 25 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C}; R_{GS} = 50 \Omega$	[2]	-	87	А

^{[1] 150}A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Protected by 100% test

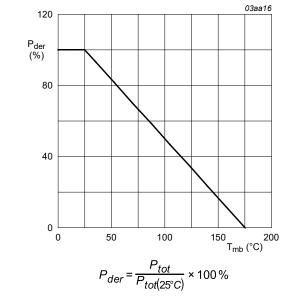
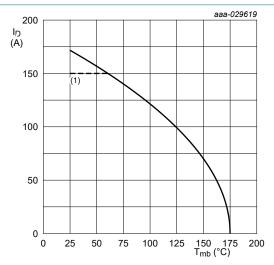


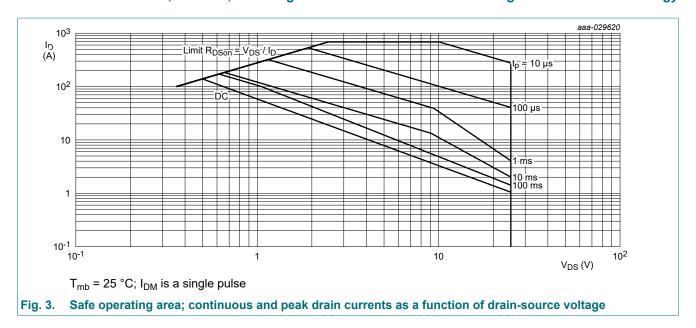
Fig. 1. Normalized total power dissipation as a function of mounting base temperature



 $V_{GS} \ge 10 \text{ V}$

(1) 150A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

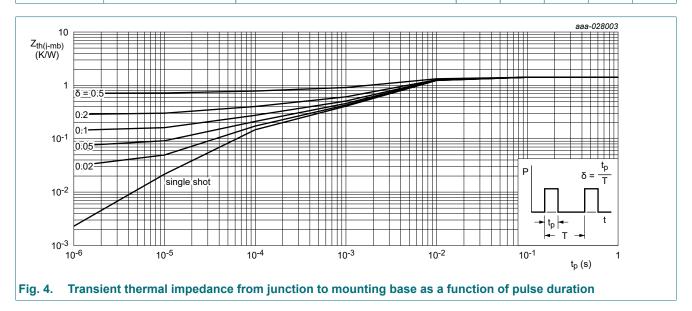
Fig. 2. Continuous drain current as a function of mounting base temperature



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4	-	1.12	1.42	K/W
R _{th(j-a)}	thermal resistance from	Fig. 5	-	50	-	K/W
	junction to ambient	Fig. 6	-	130	-	K/W



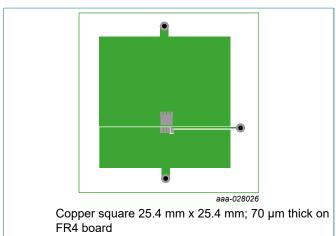
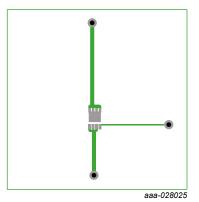


Fig. 5. PCB layout for thermal resistance from junction to ambient



70 µm thick copper on FR4 board

Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	25	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	22.5	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.2	1.73	2.2	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-4	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μΑ
		V _{DS} = 20 V; V _{GS} = 0 V; T _j = 125 °C	-	2.5	-	μΑ
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_{D} = 25 A; T_{j} = 25 °C; Fig. 10	-	1.46	1.81	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 150 °C; Fig. 11	-	-	3.2	mΩ
		V_{GS} = 4.5 V; I_{D} = 25 A; T_{j} = 25 °C; Fig. 10	-	2.1	2.7	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 150 °C; Fig. 11	-	-	4.8	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	0.5	1.2	3	Ω
Dynamic cha	racteristics				_	
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13	7.7	17	28	nC
		I _D = 25 A; V _{DS} = 12 V; V _{GS} = 10 V; Fig. 12; Fig. 13	15.8	35	58	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V; T _j = 25 °C	-	18	-	nC

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V;		1.5	5.5	10.5	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 12; Fig. 13		0.86	3.2	6.1	nC
Q _{GS(th-pl)}	post-threshold gate- source charge			0.6	2.2	4.2	nC
Q_{GD}	gate-drain charge			1	5.6	11.2	nC
V _{GS(pI)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 12 V; <u>Fig. 12</u> ; <u>Fig. 13</u>		-	2.8	-	V
C _{iss}	input capacitance	V_{DS} = 12 V; V_{GS} = 0 V; f = 1 MHz; T_j = 25 °C; Fig. 14		1267	2111	3167	pF
C _{oss}	output capacitance			872	1454	2181	pF
C _{rss}	reverse transfer capacitance	-		62	230	552	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 12 \text{ V}; R_L = 0.4 \Omega; V_{GS} = 4.5 \text{ V};$		-	14	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$		-	25	-	ns
t _{d(off)}	turn-off delay time			-	18	-	ns
t _f	fall time			-	14	-	ns
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 12 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$		-	23	-	nC
Source-dra	in diode		1				
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 15$		-	0.78	1	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$		-	30	-	ns
Q _r	recovered charge	V _{DS} = 12 V; <u>Fig. 16</u>	[1]	-	23	-	nC
t _a	reverse recovery rise time			-	16	-	ns
t _b	reverse recovery fall time			-	14	-	ns
S	softness factor			-	0.88	-	

[1] includes capacitive recovery

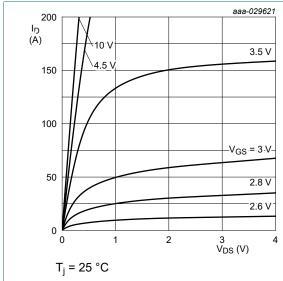


Fig. 7. Output characteristics; drain current as a function of drain-source voltage; typical values

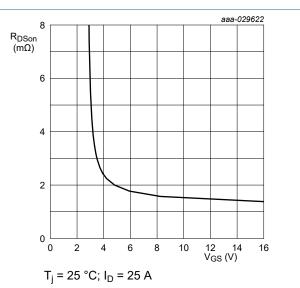


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

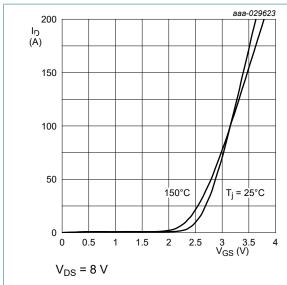


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

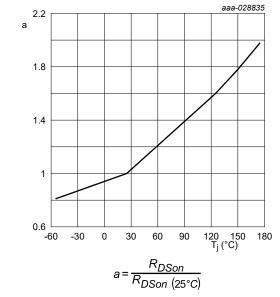


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

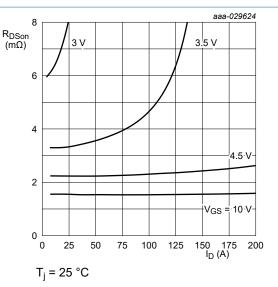


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

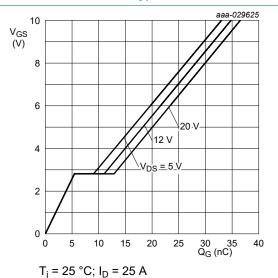


Fig. 12. Gate-source voltage as a function of gate charge; typical values

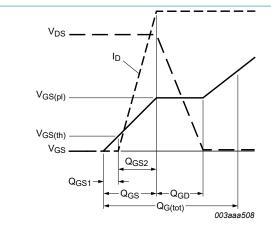


Fig. 13. Gate charge waveform definitions

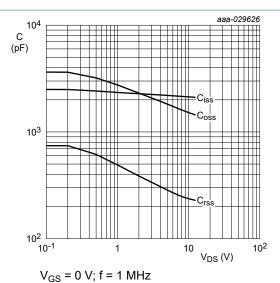


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

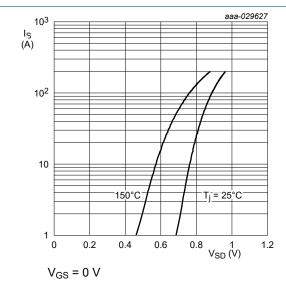


Fig. 15. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

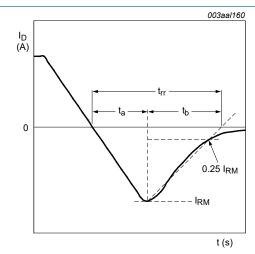
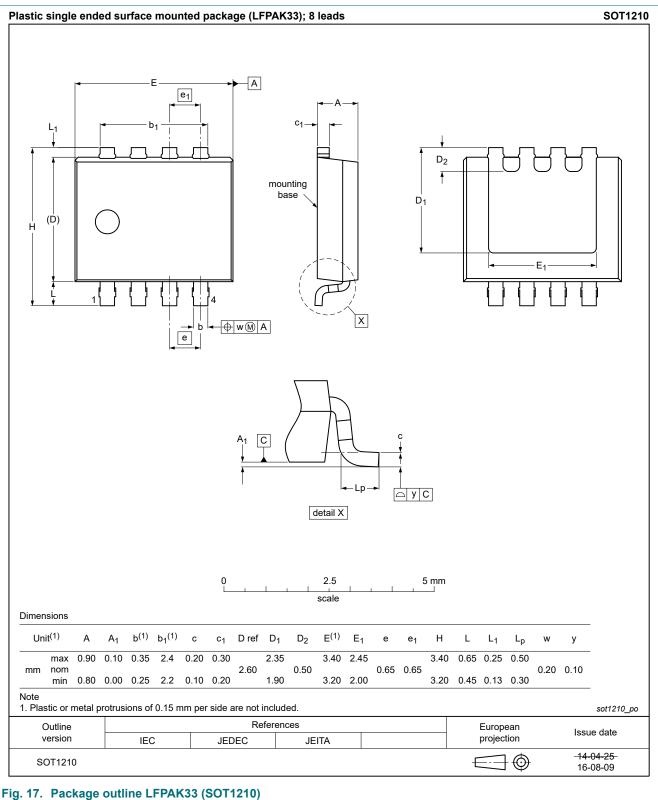


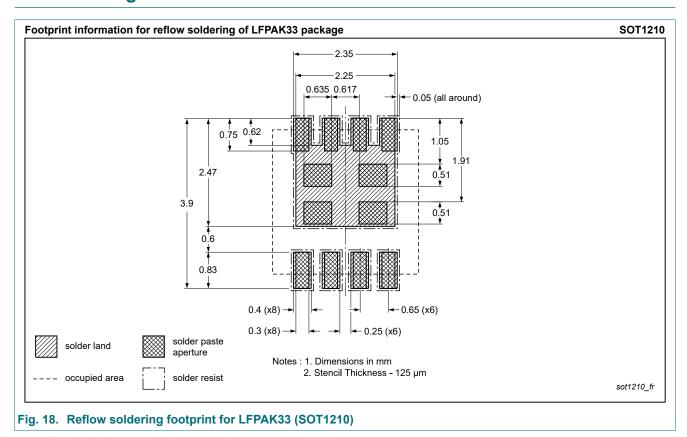
Fig. 16. Reverse recovery timing definition

11. Package outline



Tig. 17. Tackage outline EliTAROS (0011210)

12. Soldering



13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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